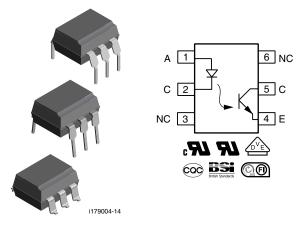
**CNY117F** 



**Vishay Semiconductors** 

# **Optocoupler, Phototransistor Output,** no Base Connection, 110 °C Rated



### DESCRIPTION

The CNY117F is a 110 °C rated optocoupler consisting of a gallium arsenide infrared emitting diode optically coupled to a silicon planar phototransistor detector in a plastic plug-in DIP-6 package.

The coupling device is suitable for signal transmission between two electrically separated circuits. The potential difference between the circuits to be coupled is not allowed to exceed the maximum permissible reference voltages.

In contrast to the CNY117 series, the base terminal of the F type is not connected, resulting in a substantially improved common-mode interference immunity.

### **FEATURES**

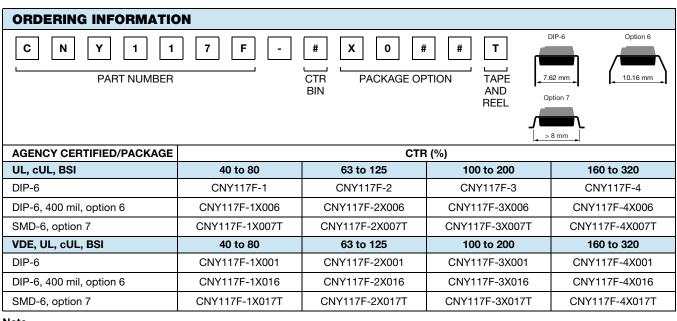
- Operating temperature from -55 °C to +110 °C
- No base terminal connection for improved common mode interface immunity
- · Long term stability
- Industry standard dual-in-line package
- COMPLIANT • Material categorization: For definitions of compliance please see www.vishay.com/doc?99912

#### **APPLICATIONS**

- AC adapter
- SMPS
- PLC
- Factory automation
- · Game consoles

### AGENCY APPROVALS

- UL file no. E52744
- cUL tested to CSA 22.2 bulletin 5A
- DIN EN 60747-5-5 (VDE 0884-5), available with option 1
- BSI: EN 60065, EN 60950-1
- FIMKO EN60950
- CQC GB8898-2011



Note

Additional options may be possible, please contact sales office.

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RoHS





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<b>ABSOLUTE MAXIMUM RATINGS</b> (T <sub>amb</sub> = 25 °C, unless otherwise specified)									
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT					
INPUT									
Reverse voltage		V <sub>R</sub>	6.0	V					
DC forward current		I <sub>F</sub>	60	mA					
Surge forward current	t ≤ 10 µs	I <sub>FSM</sub>	2.5	А					
Power dissipation		P <sub>diss</sub>	100	mW					
OUTPUT									
Collector emitter breakdown voltage		BV <sub>CEO</sub>	70	V					
Collector current		Ι <sub>C</sub>	50	mA					
Collector peak current	$t_p/T = 0.5, t_p \le 10 \text{ ms}$	I <sub>CM</sub>	100	mA					
Output power dissipation		P <sub>diss</sub>	150	mW					
COUPLER									
Isolation test voltage between emitter and detector	t = 1 min	V <sub>ISO</sub>	5000	V <sub>RMS</sub>					
Storage temperature range		T <sub>stg</sub>	-55 to +150	°C					
Ambient temperature range		T <sub>amb</sub>	-55 to +110	°C					
Soldering temperature <sup>(1)</sup>	2 mm from case, $\leq$ 10 s	T <sub>sld</sub>	260	°C					
Total power dissipation		P <sub>diss</sub>	250	mW					

#### Notes

Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not
implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute
maximum ratings for extended periods of the time can adversely affect reliability.

<sup>(1)</sup> Refer to reflow profile for soldering conditions for surface mounted devices (SMD). Refer to wave profile for soldering conditions for through hole devices (DIP).

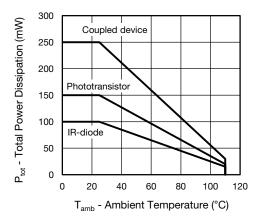


Fig. 1 - Total Power Dissipation vs. Ambient Temperature

<b>ELECTRICAL CHARACTERISTICS</b> (T <sub>amb</sub> = 25 °C, unless otherwise specified)							
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
INPUT							
Forward voltage	$I_F = 60 \text{ mA}$		V <sub>F</sub>		1.39	1.65	V
Breakdown voltage	I <sub>R</sub> = 10 μA		V <sub>BR</sub>	6.0			V
Reverse current	V <sub>R</sub> = 6.0 V		I <sub>R</sub>		0.01	10	μA
Capacitance	V <sub>R</sub> = 0 V, f = 1.0 MHz		Co		25		pF
OUTPUT							
Collector emitter capacitance	V <sub>CE</sub> = 5.0 V, f = 1.0 MHz		C <sub>CE</sub>		5.2		pF
Base collector capacitance	V <sub>CE</sub> = 5.0 V, f = 1.0 MHz		C <sub>BC</sub>		6.5		pF
Emitter base capacitance	V <sub>CE</sub> = 5.0 V, f = 1.0 MHz		C <sub>EB</sub>		7.5		pF

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ELECTRICAL CHARACTERISTICS (T <sub>amb</sub> = 25 °C, unless otherwise specified)								
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT	
COUPLER								
Collector emitter, saturation voltage	$I_F = 10 \text{ mA}, I_C = 2.5 \text{ mA}$		V <sub>CEsat</sub>		0.25	0.4	V	
Coupling capacitance			CC		0.6		pF	
Collector emitter, leakage current	V <sub>CE</sub> = 10 V	CNY117F-1	I <sub>CEO</sub>		2.0	50	nA	
		CNY117F-2	I <sub>CEO</sub>		2.0	50	nA	
		CNY117F-3	I <sub>CEO</sub>		5.0	100	nA	
		CNY117F-4	I <sub>CEO</sub>		5.0	100	nA	

#### Note

 Minimum and maximum values were tested requierements. Typical values are characteristics of the device and are the result of engineering evaluations. Typical values are for information only and are not part of the testing requirements.

CURRENT TRANSFER RATIO (T <sub>amb</sub> = 25 °C, unless otherwise specified)								
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT	
Current transfer ratio	I <sub>F</sub> = 10 mA I <sub>F</sub> = 1.0 mA	CNY117F-1	CTR	40		80	%	
		CNY117F-2	CTR	63		125	%	
		CNY117F-3	CTR	100		200	%	
		CNY117F-4	CTR	160		320	%	
		CNY117F-1	CTR	13	30		%	
		CNY117F-2	CTR	22	45		%	
		CNY117F-3	CTR	34	70		%	
		CNY117F-4	CTR	56	90		%	

#### Note

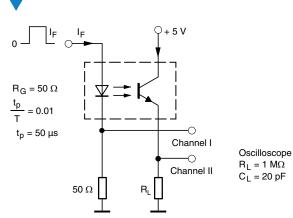
• Current transfer ratio  $I_C/I_F$  at  $V_{CE}$  = 5.0 V, 25 °C and collector emitter leakage current by dash number.

SWITCHING CHARACTERISTICS (T <sub>amb</sub> = 25 °C, unless otherwise specified)								
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT	
LINEAR OPERATION (with	out saturation)	<u>.</u>						
Turn-on time	$I_{F} = 10 \text{ mA}, \text{ V}_{CC} = 5.0 \text{ V}, \\ \text{R}_{L} = 75 \ \Omega$		t <sub>on</sub>		3.0		μs	
Rise time	$I_{F} = 10 \text{ mA}, \text{ V}_{CC} = 5.0 \text{ V}, \\ R_{L} = 75 \Omega$		t <sub>r</sub>		2.0		μs	
Turn-off time	$I_{F} = 10 \text{ mA}, \text{ V}_{CC} = 5.0 \text{ V}, \\ \text{R}_{L} = 75 \ \Omega$		t <sub>off</sub>		2.3		μs	
Fall time	$I_{F} = 10 \text{ mA}, \text{ V}_{CC} = 5.0 \text{ V}, \\ \text{R}_{L} = 75 \ \Omega$		t <sub>f</sub>		2.0		μs	
Cut-off frequency	$I_{F} = 10 \text{ mA}, \text{ V}_{CC} = 5.0 \text{ V}, \\ \text{R}_{L} = 75 \ \Omega$		f <sub>CO</sub>		110		kHz	
SWITCHING OPERATION	(with saturation)	<u>.</u>						
	I <sub>F</sub> = 20 mA	CNY117F-1	t <sub>on</sub>		3.0		μs	
Turn-on time	I <sub>F</sub> = 10 mA	CNY117F-2	t <sub>on</sub>		4.2		μs	
	$I_F = 10 IIIA$	CNY117F-3	t <sub>on</sub>		4.2		μs	
	I <sub>F</sub> = 5.0 mA	CNY117F-4	t <sub>on</sub>		6.0		μs	
	I <sub>F</sub> = 20 mA	CNY117F-1	t <sub>r</sub>		2.0		μs	
Rise time	I <sub>F</sub> = 10 mA	CNY117F-2	t <sub>r</sub>		3.0		μs	
	IF = 10 IIIA	CNY117F-3	t <sub>r</sub>		3.0		μs	
	I <sub>F</sub> = 5.0 mA	CNY117F-4	t <sub>r</sub>		4.6		μs	
	I <sub>F</sub> = 20 mA	CNY117F-1	t <sub>off</sub>		18		μs	
Turn-off time	I <sub>F</sub> = 10 mA	CNY117F-2	t <sub>off</sub>		23		μs	
rum-on ume	$I_F = 10 IIIA$	CNY117F-3	t <sub>off</sub>		23		μs	
	I <sub>F</sub> = 5.0 mA	CNY117F-4	t <sub>off</sub>		25		μs	
Fall time	I <sub>F</sub> = 20 mA	CNY117F-1	t <sub>f</sub>		11		μs	
	I_ = 10 mA	CNY117F-2	t <sub>f</sub>		14		μs	
	I <sub>F</sub> = 10 mA		t <sub>f</sub>		14		μs	
	I <sub>F</sub> = 5.0 mA	CNY117F-4	t <sub>f</sub>		15		μs	

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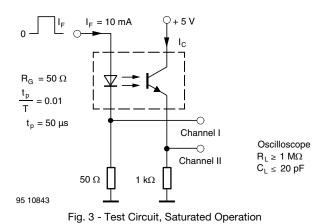


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Fig. 2 - Test Circuit, Non-Saturated Operation



 $\mathbf{I}_{\mathsf{F}}$ 0 t<sub>p</sub> t  $I_{\rm C}$ 100 % 90 % 10 % 0 t tf t. t<sub>on</sub>  $egin{aligned} t_p \ t_d \ t_r \ t_{on} \ (= t_d + t_r) \end{aligned}$ Pulse duration Storage time t<sub>s</sub> Delay time Fall time tf Turn-off time Rise time  $= t_s + t_f$ l<sub>off</sub> Turn-on time 96 11698

Fig. 4 - Switching Times

SAFETY AND INSULATION	RATINGS			
PARAMETER		SYMBOL	VALUE	UNIT
MAXIMUM SAFETY RATINGS				·
Output safety power		P <sub>SO</sub>	700	mW
Input safety current		I <sub>SI</sub>	400	mA
Safety temperature		T <sub>SI</sub>	175	°C
Comparative tracking index		CTI	175	
INSULATION RATED PARAMETER	S			÷
Maximum withstanding isolation volt	age	V <sub>ISO</sub>	5000	V <sub>RMS</sub>
Maximum transient isolation voltage		V <sub>IOTM</sub>	8000	V <sub>peak</sub>
Maximum repetitive peak isolation ve	bltage	V <sub>IORM</sub>	890	V <sub>peak</sub>
Insulation resistance	$T_{amb} = 25 \text{ °C}, V_{DC} = 500 \text{ V}$	R <sub>IO</sub>	≥ 10 <sup>12</sup>	Ω
Isolation resistance	$T_{amb} = 100 \ ^{\circ}C, V_{DC} = 500 \ V$	R <sub>IO</sub>	≥ 10 <sup>11</sup>	Ω
Climatic classification (according to IEC 68 part 1)			55/115/21	
Environment (pollution degree in acc	ordance to DIN VDE 0109)		2	
Creenage distance	Standard DIP-4		≥7	mm
Creepage distance	SMD		≥7	mm
	Standard DIP-4		≥ 8	mm
Clearance distance	SMD		≥ 8	mm
Insulation thickness	•	DTI	≥ 0.4	mm

#### Note

• As per DIN EN 60747-5-5, § 7.4.3.8.2, this optocoupler is suitable for "safe electrical insulation" only within the safety ratings. Compliance with the safety ratings shall be ensured by means of protective circuits.

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# **TYPICAL CHARACTERISTICS** ( $T_{amb} = 25$ °C, unless otherwise specified)

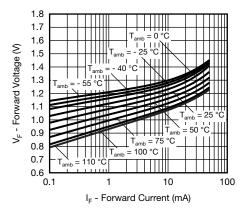


Fig. 5 - Forward Voltage vs. Forward Current

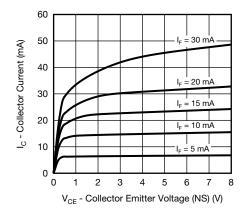


Fig. 6 - Collector Current vs. Collector Emitter Voltage (NS)

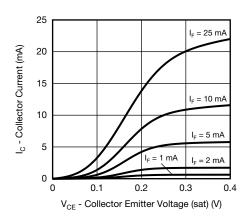


Fig. 7 - Collector Current vs. Collector Emitter Voltage (sat)

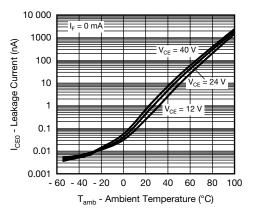


Fig. 8 - Leakage Current vs. Ambient Temperature

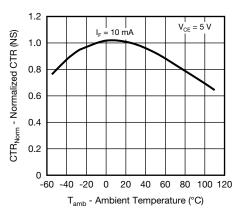


Fig. 9 - Normalized CTR (NS) vs. Ambient Temperature

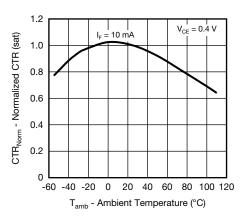


Fig. 10 - Normalized CTR (sat) vs. Ambient Temperature

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5 questions, contact: optocoupleranswers@ Document Number: 83598





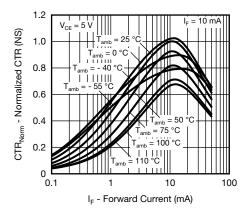


Fig. 11 - Normalized CTR (NS) vs. Forward Current

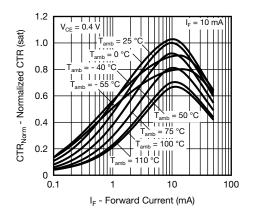


Fig. 12 - Normalized CTR (sat) vs. Forward Current

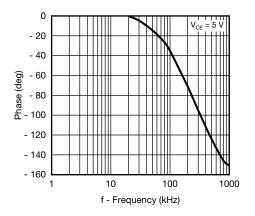


Fig. 13 - CTR Frequency vs. Phase Angle

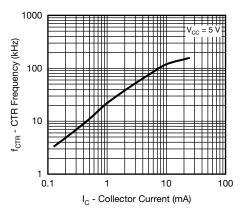


Fig. 14 - CTR -3 dB Frequency vs. Collector Current

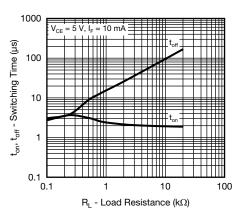
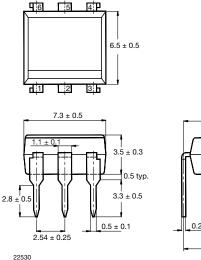
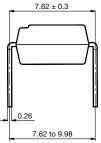


Fig. 15 - Switching Time vs. Load Resistance



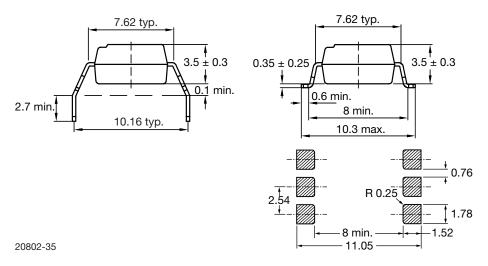
### **PACKAGE DIMENSIONS** in millimeters





**Option 6** 

**Option 7** 



## PACKAGE MARKING (Example of CNY117F-2X017T)

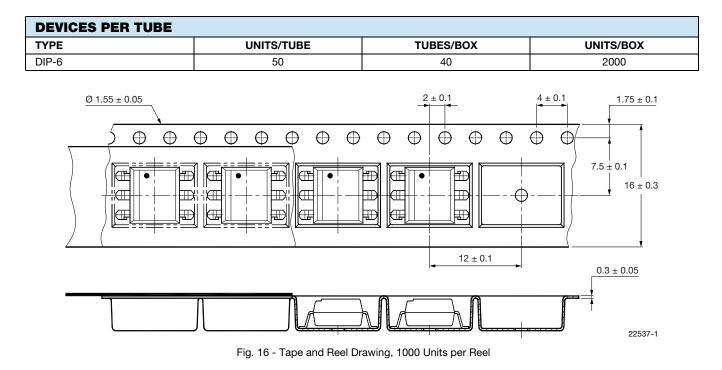


#### Notes

- VDE logo is only marked on option 1 parts. Option information is not marked on the part.
- Tape and reel suffix (T) is not part of the package marking.



### **TUBE AND TAPE INFORMATION**





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